BY329 series

### **GENERAL DESCRIPTION**

# Glass-passivated double diffused rectifier diodes in a plastic envelope featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

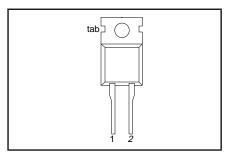
### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BY329	-800	-1000	-1200	
$V_{RRM}$	Repetitive peak reverse voltage	800	1000	1200	V
I <sub>F(AV)</sub>	Average forward current	8	8	8	Α
I <sub>FSM</sub>	Non-repetitive peak forward current	75	75	75	А
t <sub>rr</sub>	Reverse recovery time	135	135	135	ns

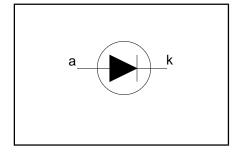
### **PINNING - TO220AC**

PIN	DESCRIPTION
1	cathode (k)
2	anode (a)
tab	cathode (k)

### **PIN CONFIGURATION**



### **SYMBOL**



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
$V_{RSM}$	Non-repetitive peak reverse voltage		1	<b>-800</b> 800	<b>-1000</b> 1000	<b>-1200</b> 1200	٧
$egin{array}{c} V_{RRM} \ V_{RWM} \end{array}$	Repetitive peak reverse voltage Crest working reverse voltage		-	800 600	1000 800	1200 1000	V V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{mb} \le 122 ^{\circ}C$	-		8		Α
		sinusoidal; a = 1.57; $T_{mb} \le 125 ^{\circ}C$	-		7		Α
I <sub>F(RMS)</sub>	RMS forward current	IIID	-		11		Α
I <sub>FRM</sub>	Repetitive peak forward current	$t = 25 \mu s$ ; $δ = 0.5$ ; $T_{mb} \le 122 °C$	-		16		Α
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10 ms	-		75		Α
16	current.	t = 8.3 ms sinusoidal; T <sub>j</sub> = 150 °C prior to surge; with reapplied V <sub>RWM(max)</sub>			82		А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms	-		28		$A^2s$
$T_{\text{stg}}$	Storage temperature		-40		150		°C
$T_{j}^{sig}$	Operating junction temperature		-		150		°C

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<sup>1</sup> Neglecting switching and reverse current losses.

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### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to mounting base		-	-	2.0	K/W
R <sub>th j-a</sub>		in free air.	-	60	-	K/W

### STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

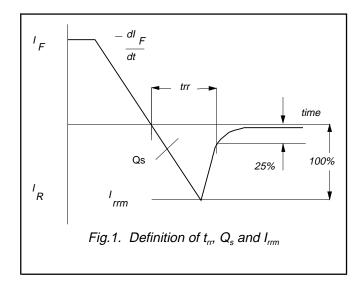
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	$I_F = 20 \text{ A}$	-	1.5	1.85	V
I <sub>R</sub>	Reverse current	$V_R = V_{RWM}$ ; $T_i = 125 \text{ °C}$		0.1	1.0	mA

### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\begin{matrix} t_{rr} \\ Q_s \\ dI_R/dt \end{matrix}$	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$		100 0.5 50	135 0.7 60	ns μC A/μs

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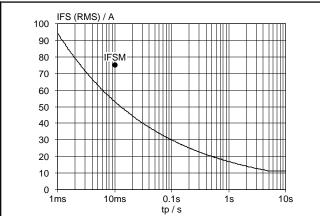


Fig.4. Maximum non-repetitive rms forward current.  $I_F = f(t_p)$ ; sinusoidal current waveform;  $T_j = 150^{\circ}\text{C}$  prior to surge with reapplied  $V_{RWM}$ .

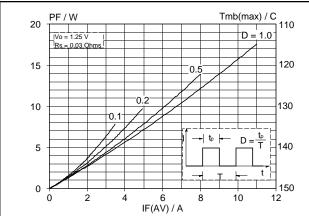


Fig.2. Maximum forward dissipation,  $P_F = f(I_{F(AV)})$ ; square wave current waveform; parameter D = duty cycle =  $t_p/T$ .

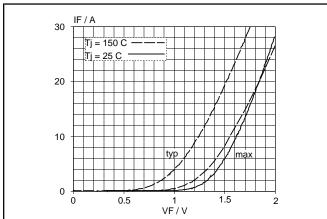


Fig.5. Typical and maximum forward characteristic;  $I_F = f(V_F)$ ; parameter  $T_i$ 

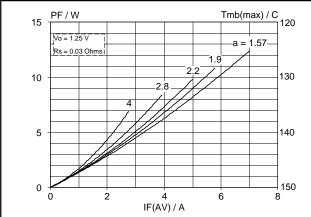
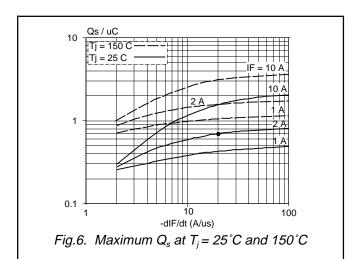


Fig.3. Maximum forward dissipation,  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform; parameter a = form factor  $= I_{F(RMS)}/I_{F(AV)}$ .



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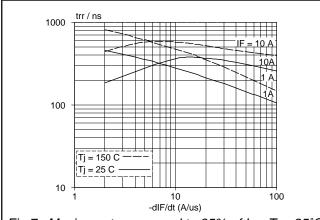
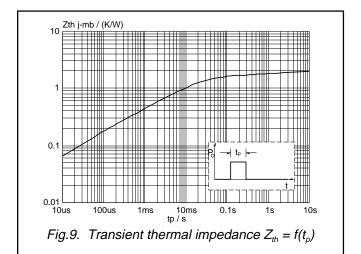


Fig.7. Maximum  $t_{rr}$  measured to 25% of  $I_{rrm}$ ;  $T_j = 25^{\circ}C$  and 150°C



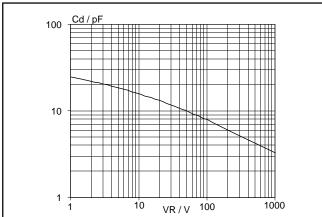
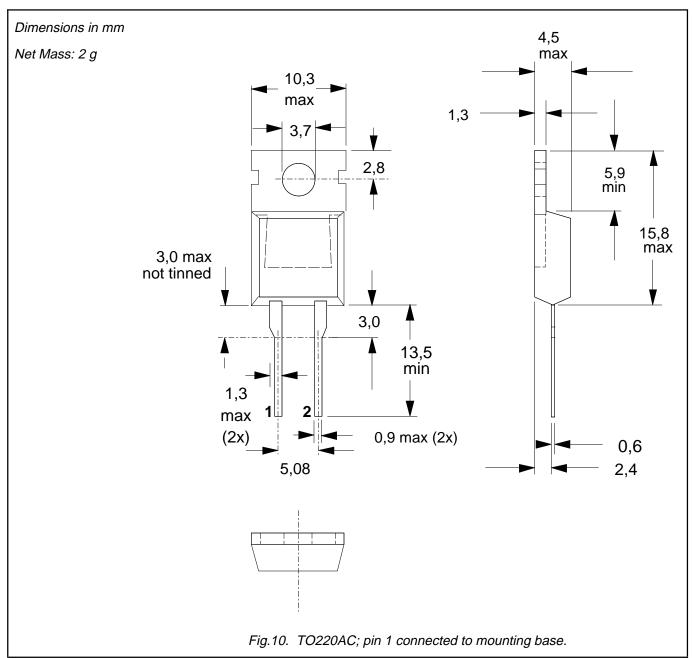


Fig.8. Typical junction capacitance  $C_d$  at f = 1 MHz,  $T_j = 25^{\circ}C$ 

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### **MECHANICAL DATA**



- Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
  Epoxy meets UL94 V0 at 1/8".

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### **DEFINITIONS**

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification This data sheet contains final product specifications.					

### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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